

NOISE

- * Any unwanted signal is considered as noise.
- * Noise tends to interfere with received or produced signals.
- * Examples :
 - * In receivers, several electrical disturbances produces noise and thus modifying the required signal in an unwanted form.
 - * Radio Receivers : The loudspeaker produce a hiss type sound due to noise.
 - * T. V. : The noise can be seen as snow in the displaying screen.
 - * In pulse communication : The noise may alter the pulse from +ve to -ve.
- Thus The Noise may limit the performance of a communication system.

* Generally speaking: There are External & Internal noises.

* External noise: Atmospheric noise,

External noise is that noise generated outside the communication system.

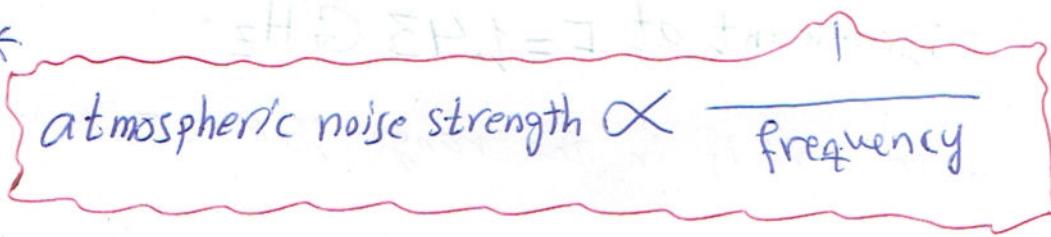
Extraterrestrial noise,
Industrial noise

* Internal noise:

Internal noise is that noise which is generated inside a communication system

Shot noise,
Partition noise,
Low frequency or Flicker noise,
High frequency or transit-time noise,
Thermal noise.

Atmospheric Noise :-

- * Atmospheric noise also called static noise.
- * Static noise produced by discharges in thunderstorms and other natural electrical disturbances of the atmosphere.
- * It is electrical impulses ∇ random in nature.
- * Atmospheric noise distributed over the complete frequency spectrum used for radio communication.
- * 
atmospheric noise strength $\propto \frac{1}{\text{frequency}}$
- * Large atmospheric noise is produced in Low & Medium frequency bands.
- * Very small noise is produced in VHF & UHF bands.
- * Atmospheric noise becomes less severe when $F > 30 \text{ MHz}$.

Extraterrestrial Noise :-

* Extraterrestrial noise also called space noise.

* Extraterrestrial noise

Solar Noise

Cosmic Noise

* Solar noise :- emanating from sun.

* Cosmic noise :- emanating from distant stars and galaxies.

* Cosmic noise also called space noise.

* Cosmic noise is significant at $F = 1.43 \text{ GHz}$.

* However, cosmic noise exists in the range $15 \text{ MHz} - 100 \text{ GHz}$.

Industrial Noise :- (Manmade Noise)

* Industrial or manmade noise is due to :-

* Automobile & aircraft ignition,

* electrical motors,

* switch gears and leakage from high voltage transmission lines

* other heavy electrical equipments.

* Manmade noise extending in the range $1 \text{ MHz} - 600 \text{ MHz}$.

Shot Noise :-

- * Arises in active devices due to random behaviour of charge carriers.

- Electron tubes,
- Semiconductor devices
- Solid state devices

- * Shot Noise current is given by

$$i(t) = I_0 + i_n(t)$$

where I_0 is the mean (constant)

and $i_n(t)$ is the shot (fluctuating) noise.

- * $i_n(t)$ is random (indeterministic), therefore it can be specified by its power density spectrum.

- * Power density spectrum of $i(t)$ is

$$i_n(t) \xleftrightarrow{\text{F.T.}} S_i(\omega) = q I_0$$

where q is electronic charge,

and I_0 is the mean value.

- * The transit time of an electron in a diode is

$$\tau = 3.36 * \frac{d}{\sqrt{V}}$$

μsecond

d = distance between cathode and anode

V = voltage across diode

Partition Noise%

- * generated in a circuit when a current has to divide between two or more paths.
- * Hence, diode less noise than a BJT transistor.
- * Metal-Oxide Semiconductor Field Effect Transistor MOSFET transistor less noise than BJT transistor because the gate draws zero current.
- * Therefore, MOSFET used in Low noise microwave amplification.

Flicker Noise

- * also called Low-frequency noise
- * also known as $1/f$ noise
- * power spectral density inversely proportional to the frequency.
$$F \propto \frac{1}{S(w)}$$
 - As Frequency decreases \rightarrow noise increases.
- As Frequency increases \rightarrow noise decreases.
- * Flicker noise generated from fluctuation in the carrier density.

Transit-Time noise

- * Also called High-frequency noise.
- * Generated when charge-carriers crossing a junction.
- * Generated when charge-carriers diffuse back to the source.
- * Some charge-carriers diffuse back, input admittance increases.
- * When diffusing back, input admittance increases.
- * power spectral density $\propto F$

Thermal Noise :-

* Also called as :-

i) White noise,

ii) Johnson noise,

iii) KTB noise

* Generated randomly in a resistor or resistive components of complex impedances due to rapid and random motion of the molecules, atoms of electrons.

* Maximum noise power of a resistor is :-

$$P_n \propto T \cdot B$$

or

$$P_n = k \cdot T \cdot B$$

where $k = \text{Boltzmann's constant} = 1.38 \times 10^{-23} \text{ J/deg.K}$

$T = \text{Absolute temperature.} = (\text{ambient temperature} + 273)^\circ\text{K}$

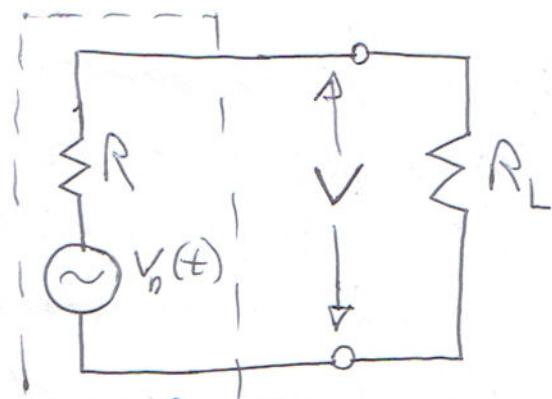
$B = \text{Bandwidth of operation in Hz.}$

Noisy Resistor

- * Thermal or Johnson or white noise generated in a noisy resistor is random and has zero average (dc) value.

- * If a very sensitive AC-Voltmeter connected across a resistor in temperature of 27°C (room temperature = $27^\circ\text{C} + 273 = 300^\circ\text{K}$), then some rms voltage can be captured, this is the noise voltage.

- * Voltage model of a noisy resistor



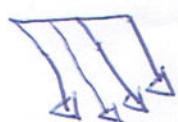
- * According to maximum power transfer theorem:-

$$R_L = R$$

$$P_n = \frac{V^2}{R}$$

- * Using voltage divider rule : $V = \frac{V_n}{2}$

$$\therefore P_n = \frac{V_n^2}{4R}$$



* Since $P_n = kTB$

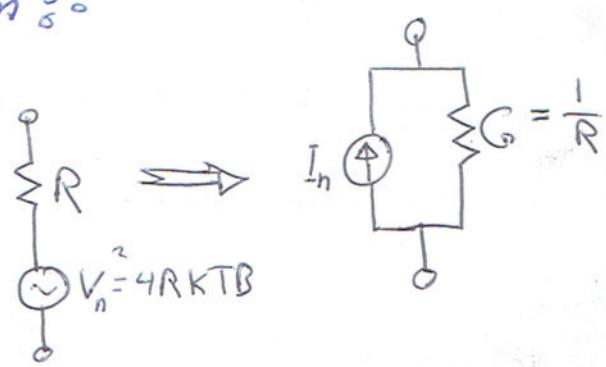
$$\therefore V_n = \sqrt{4RkTB}$$

sub 2.1) into = jgjw1a=1g

* Using Norton's theorem

and let $G = \frac{1}{R}$

$$\therefore I_n = \sqrt{4GkTB}$$



Ex. 1: An amplifier operating over the frequency range 18-20 MHz has a 10 k Ω input resistor. Calculate the rms noise voltage at the input to this amplifier if the ambient temperature is 27°C.

Solution: Boltzmann's constant $k = 1.38 \times 10^{-23} \text{ J/deg.K}$

$$R = 10 \text{ k}\Omega$$

$$T = 27 + 273 = 300^\circ\text{K}$$

$$\text{Bandwidth } B = 20 - 18 = 2 \text{ MHz}$$

$$V_n = \sqrt{4kRTB} = \sqrt{4 \times 10000 \times 1.38 \times 10^{-23} \times 300 \times 2 \times 10^6}$$

$$= \sqrt{8 \times 10^{10} \times 300 \times 1.38 \times 10^{-23}}$$

$$\approx 18.199 \mu\text{Volts.}$$

Ex. 2

Calculate the rms noise voltage at the input of a video amplifier using a device having $300\text{ }\Omega$ equivalent noise resistance and $400\text{ }\Omega$ input resistance. It is given that the bandwidth of the amplifier is 7 MHz and the ambient temperature is 27°C . Note that the two resistors are connected in series.

Solution $T = 27^\circ\text{C} + 273 = 300^\circ\text{K}$.

$$R_{\text{series}} = R_s = R_1 + R_2 = 700\text{ }\Omega$$

$$B = 7 \times 10^6 \text{ Hz}$$

$$V_{n_t} = \sqrt{4R_s k T B} = \sqrt{4 \times 700 \times 1.38 \times 10^{-23} \times 300 \times 7 \times 10^6}$$

$$V_{n_t} \approx 9 \mu\text{V}$$

Ex. 3 Two resistors of $20\text{ k}\Omega$ and $50\text{ k}\Omega$ are connected in parallel when the room temperature was 15°C or 290 K . For a given bandwidth of 100 kHz , determine the thermal noise voltage generated by: (a) each resistor (b) the two resistors in parallel.

$$\text{Solution: (a)} V_{n_1} = \sqrt{4 \times 20 \times 10^3 \times 1.38 \times 10^{-23} \times 290 \times 100 \times 10^3} \approx 5.66 \mu\text{V}$$

$$V_{n_2} = \sqrt{4 \times 50 \times 10^3 \times 1.38 \times 10^{-23} \times 290 \times 100 \times 10^3} \approx 8.95 \mu\text{V}$$

$$(b) \text{ in parallel } R_{\text{parallel}} = R_p \approx 14.2857 \text{ k}\Omega$$

$$V_{n_p} = \sqrt{4 \times 14.2857 \times 10^3 \times 1.38 \times 10^{-23} \times 290 \times 100 \times 10^3}$$

$$V_{n_p} \approx 4.78 \mu\text{V}$$

Ex. What will be the thermal noise power density of a resistor in room temperature $T = 290 \text{ K}$ under maximum power transfer conditions?

Solution. $T = 290 \text{ K}$

$$P_n = 4RKB \quad] \text{ under maximum power transfer should divide by } 4R.$$

$$\frac{P_n}{4RB} = KT = 4.002 \times 10^{-21} \frac{\text{W}}{\text{Hz}}$$

* For communication system analysis, power ratio in decibels (dB) is usually used.

$$* 1 \text{ watt} = 10 \log_{10} \left(\frac{P_{\text{watts}}}{1 \text{ watt}} \right)$$

$$= 10 \log_{10} \left(\frac{1}{1} \right) = 10 \log_{10} (1)$$

$$= 0 \text{ dBW}$$

$$* 1 \text{ mWatt} = 10 \log_{10} \left(\frac{P_{\text{mWatt}}}{1 \text{ mW}} \right)$$

$$= 10 \log_{10} \left(\frac{1 \text{ mW}}{1 \text{ mW}} \right)$$

$$= 10 \log_{10} (1)$$

$$= 0 \text{ dBm}$$

$$* \text{EX. } 13 \text{ W} = 10 \log_{10} \left(\frac{13 \text{ W}}{1 \text{ W}} \right) = \log_{10} (13) \approx 11.14 \text{ dBW}$$

$$50 \text{ mW} = 10 \log_{10} \left(\frac{50 \text{ mW}}{1 \text{ mW}} \right) = \log_{10} (50) \approx 17 \text{ dBm}$$

$$13 \text{ W} = 10 \log_{10} \left(\frac{13000 \text{ mW}}{1 \text{ mW}} \right) = \log_{10} (13000) \approx 41.14 \text{ dBm}$$

Signal-to-Noise Ratio ; \circ (SNR)

- * The ratio of Signal power to the Noise power at the same band of frequency is called Signal-to-Noise Ratio (SNR) or (S/N).

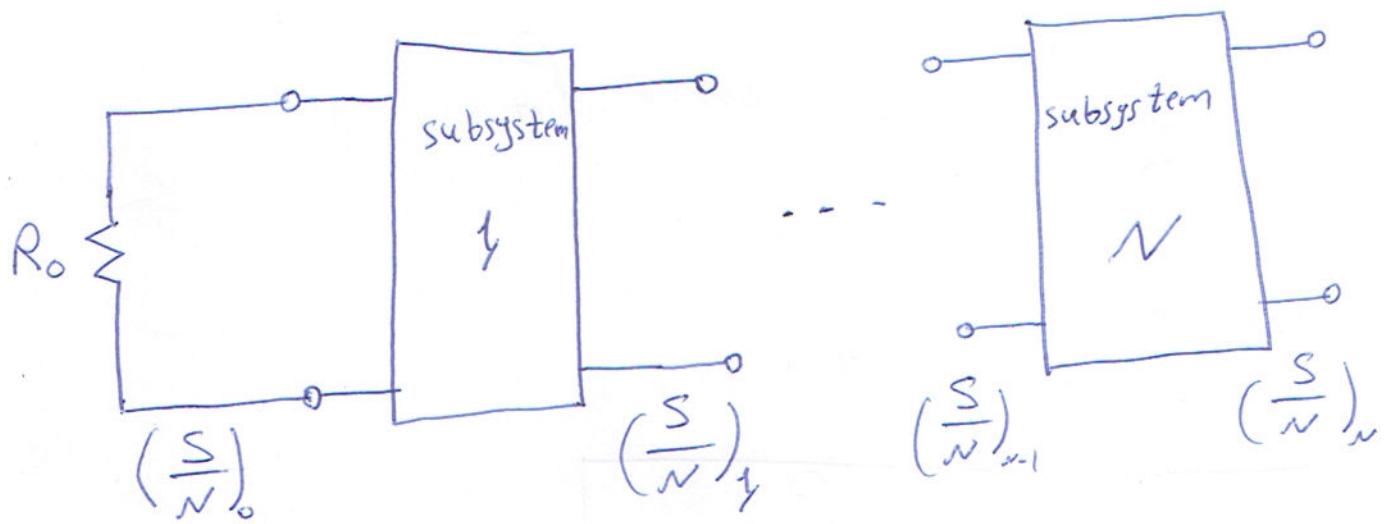
$$\frac{S}{N} = \frac{\text{Signal power}}{\text{Noise power}} = \frac{\text{Power spectrum density of signal}}{\text{Power spectrum density of noise}}$$

Noise Factor ; \circ

- * Also called noise Figure.
- * Noise figure is defined as:-

$$NF = \frac{\text{Input SNR}}{\text{output SNR}} = \frac{SNR_i}{SNR_o}$$

- * Systems are usually represented as subsystems connected in cascade form.
- * Assuming output impedance of a certain system is equal to the input impedance of the next system. (usually $50\text{-}\Omega$).



- * Now, For the l^{th} subsystem, noise figure F_l is

$$\left(\frac{S}{N}\right)_l = \frac{1}{F_l} \left(\frac{S}{N}\right)_{l-1}$$

- * Assuming that the l^{th} subsystem has gain G_a , then

$$P_{nl} = G_a P_{nl-1} \quad \text{Assuming the system is linear}$$

$$\therefore \left(\frac{S}{n}\right)_l = \frac{1}{F_l} \left(\frac{S}{n}\right)_{l-1}$$

and

$$F_l = \frac{P_{n,l}}{G_a P_{n,l-1}} = \frac{P_{n,l}}{G_a K T B}$$

* Considering the internal power $P_{int,l}$

$$P_{n,l} = G_a P_{n,l-1} + P_{int,l}$$

$$\boxed{F_l = f + \frac{P_{int,l}}{G_a K T B}}$$

Noise Temperature

* Equivalent Noise Temperature of a system is :-

$$\boxed{T_n = \frac{P_{n,max}}{K B}}$$

* $P_{n,max}$ is the maximum noise power of the source into bandwidth B .

Effective Noise Temperature

* effective noise temperature of subsystem l is

$$T_e = \frac{P_{int,l}}{G_a K B}$$

$$F_l = 1 + \frac{P_{int,l}}{G_a K T_0 B} = 1 + \frac{T_e}{T_0}$$

where $T_0 = 290 \text{ K.} = T + 273$

* We can express $P_{n,l}$ as

$$P_{n,l} = G_a K B (T_e + T)$$

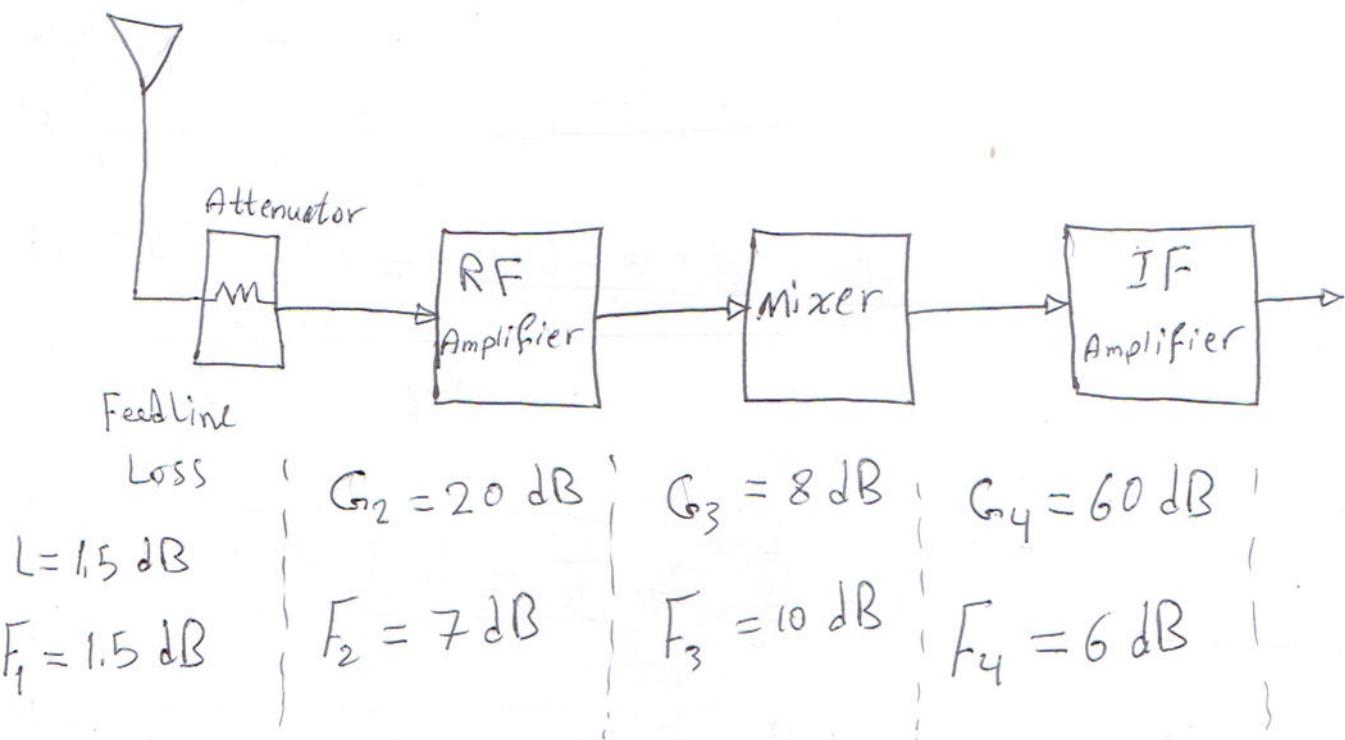
* In general for an arbitrary number of stages
of subsystems (Friis' Formula)

$$F = F_1 + \frac{F_2 - 1}{G_{a1}} + \frac{F_3 - 1}{G_{a1} G_{a2}} + \frac{F_4 - 1}{G_{a1} G_{a2} G_{a3}} \dots$$

$$T_e = T_{e1} + \frac{T_{e2}}{G_{a1}} + \frac{T_{e3}}{G_{a1} G_{a2}} + \frac{T_{e4}}{G_{a1} G_{a2} G_{a3}} \dots$$

* An attenuator of x dB means an attenuator
has a noise figure of $-x$ dB.

Ex.1 For a receiver system, the antenna was connected to an RF-amplifier with feedline loss of 1.5 dB. The RF-amplifier has gain = 20 dB and noise factor of 1.5 dB. The RF-amplifier has been connected to a mixer of gain = 7 dB and noise figure = 10 dB; the IF-amplifier of gain = 8 dB and noise figure = 6 dB. was connected to the output of the mixer, when the IF-amplifier has gain = 60 dB and noise figure = 6 dB. Calculate the system noise figure and the system's effective temperature at 290 K.



Solution

$$G_1 = 1.5 \text{ dB}, G_2 = 20 \text{ dB}, G_3 = 8 \text{ dB}, G_4 = 60 \text{ dB}.$$

$$F_1 = 1.5 \text{ dB}, F_2 = 7 \text{ dB}, F_3 = 10 \text{ dB}, F_4 = 6 \text{ dB}.$$

$$G_{\text{dB}} = 10 \log_{10} G \Rightarrow \log_{10} G = \frac{G_{\text{dB}}}{10} \Rightarrow G = 10^{\frac{G_{\text{dB}}}{10}}$$

* we have $G_1 = L = \text{losses} = 1.5 \text{ dB}$, hence it is -1.5 dB

$$\therefore G_1 = 10^{-\frac{1.5}{10}} = 0.70795 \quad \left| \begin{array}{l} F_1 = 10^{\frac{1.5}{10}} = 1.41 \\ F_2 = 10^{\frac{7}{10}} = 5.01 \\ F_3 = 10^{\frac{10}{10}} = 10 \\ F_4 = 10^{\frac{6}{10}} = 3.98 \end{array} \right.$$

$$G_2 = 10^{\frac{20}{10}} = 100.$$

$$G_3 = 10^{\frac{8}{10}} = 6.3.$$

$$G_4 = 10^{\frac{60}{10}} = 10^6 = 1000000.$$

The system noise figure is

$$F = 1.41 + \frac{5.01 - 1}{0.707} + \frac{10 - 1}{0.707 \times 100} + \frac{3.98 - 1}{0.707 \times 100 \times 6.3} = 7.19 \text{ or } 8.57 \text{ dB}$$

The effective noise temperature is

$$F = \frac{T_e}{T_0} + 1 \Rightarrow F - 1 = \frac{T_e}{T_0} \Rightarrow T_e = T_0(F - 1)$$

$$\therefore T_e = 290(7.19 - 1) = 1796.3 \text{ K.}$$

Comments and enhancements on Ex. 1, pages [197-198].

- * To reduce the noise figure (to improve system performance), interchange the cable and RF pre-amplifier.
- * In practice this may mean locating an RF preamplifier on back of the receive antenna, as in a satellite TV receiver

$$F = 5.06 - \frac{1.41-1}{100} + \frac{10-1}{100 \times 0.707} + \frac{3.98-1}{100 \times 0.707 \times 6.3} = 5.15 \text{ or } 7.12 \text{ dB}$$

$$T_e = 1202.9 \text{ K}$$

- * Going back to the original example, let the antenna, suppose the antenna has an effective noise temperature of $T_s = 400 \text{ K}$ and the system bandwidth $B = 100 \text{ kHz}$. What is the maximum available output noise power in dBm?

$$P_n = G_a K B (T_s + T_e) \Rightarrow G_a = -1.5 + 20 + 8 + 60 = 86.5 \text{ dB}$$

$$kT_o = -174 \text{ dBm/Hz}, T_o = 290 \text{ K}$$



$$P_n = 86.5 - 174 + 10 \log_{10} \left(\frac{400 + 1796.3}{290} \right) + 10 \log_{10} 10^5$$

$$= -28.71 \text{ dBm}$$

* What will be the received signal power at the antenna terminals for a system output SNR of 20dB?

$$10 \log_{10} \left(\frac{G_a P_r}{P_n} \right) = 20$$

$$\therefore P_{r \text{ dB}} = 20 + P_n \text{ dB} - G_a \text{ dB}$$

$$= 20 + (-28.71) - 86.5$$

$$= -95.21 \text{ dBm}$$